

### STN83003

# High voltage fast-switching NPN power transistor

#### **Features**

- High voltage capability
- Very high switching speed

### **Application**

■ Electronics ballasts for fluorescent lighting

### **Description**

The device is manufactured using high voltage multi-epitaxial planar technology for high switching speeds and high voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA. The STN83003 is expressly designed for a new solution to be used in compact fluorescent lamps, where it is coupled with the STN93003, its complementary PNP transistor.

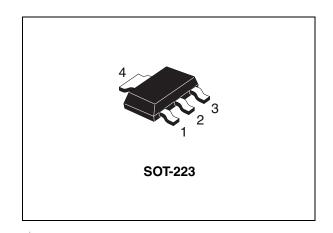


Figure 1. Internal schematic diagram

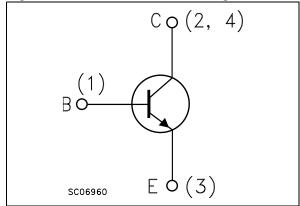


Table 1. Device summary

Part number	Marking	Package	Packaging
STN83003	N83003	SOT-223	Tape and reel

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STN83003 Electrical ratings

# 1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>CES</sub>	Collector-emitter voltage (V <sub>BE</sub> = 0)	700	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	400	V
V <sub>EBO</sub>	Emitter-base voltage $(I_C = 0, I_B = 0.75 \text{ A}, t_P < 10 \text{ µs})$	V <sub>(BR)EBO</sub>	٧
I <sub>C</sub>	Collector current	1.5	Α
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5 ms)	3	Α
I <sub>B</sub>	Base current	0.75	Α
I <sub>BM</sub>	Base peak current (t <sub>P</sub> < 5 ms)	1.5	Α
P <sub>TOT</sub>	Total dissipation at T <sub>a</sub> = 25 °C	1.6	W
T <sub>STG</sub>	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thJA</sub>	Thermal resistance junction-ambient (1) max	78	°C/W

<sup>1.</sup> Device mounted on PCB area of 1 cm<sup>2</sup>.

Electrical characteristics STN83003

## 2 Electrical characteristics

 $T_{case}$  = 25 °C unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter	Test condi	tions	Min.	Тур.	Max.	Unit
I <sub>CES</sub>	Collector cut-off current (V <sub>BE</sub> = 0)	V <sub>CE</sub> = 700 V V <sub>CE</sub> = 700 V	T <sub>C</sub> = 125 °C			1 5	mA mA
V <sub>(BR)EBO</sub>	Emitter-base breakdown voltage (I <sub>C</sub> = 0)	I <sub>E</sub> = 10 mA		12		18	V
V <sub>CE(sus)</sub> (1)	Collector-emitter sustaining voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 10 mA		400			V
V <sub>CE(sat)</sub> (1)	Collector-emitter saturation voltage	$I_C = 0.35 A$ $I_C = 0.5 A$	$I_B = 50 \text{ mA}$ $I_B = 0.1 \text{ A}$			1 0.5	<b>V</b>
V <sub>BE(sat)</sub> (1)	Base-emitter saturation voltage	I <sub>C</sub> = 0.5 A	I <sub>B</sub> = 0.1 A			1	V
h <sub>FE</sub>	DC current gain	$I_C = 10 \text{ mA}$ $I_C = 0.35 \text{ A}$ $I_C = 1 \text{ A}$	$V_{CE} = 5 V$ $V_{CE} = 5 V$ $V_{CE} = 5 V$	10 16 4	25	32	
t <sub>r</sub> t <sub>s</sub>	Resistive load Rise time Storage time Fall time	$I_C = 0.35 \text{ A}$ $I_{B1} = -I_{B2} = 70 \text{ mA}$ $I_{P} \ge 25  \mu\text{s}$	V <sub>CC</sub> = 125 V	1.5	100 2.2 0.2	2.9	ns µs µs
t <sub>s</sub>	Inductive load Storage time Fall time	$I_C = 0.5 \text{ A}$ $V_{BE(off)} = -5 \text{ V}$ $V_{Clamp} = 300 \text{ V}$	I <sub>B1</sub> = 0.1 A L = 10 mH		450 90		ns ns

<sup>1.</sup> Pulse test: pulse duration  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.

### 2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Derating curve

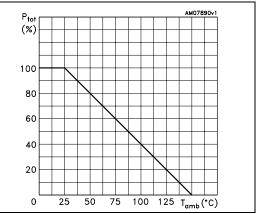


Figure 4. DC current gain  $(V_{CE} = 5 V)$ 

Figure 5. DC current gain  $(V_{CE} = 1 V)$ 

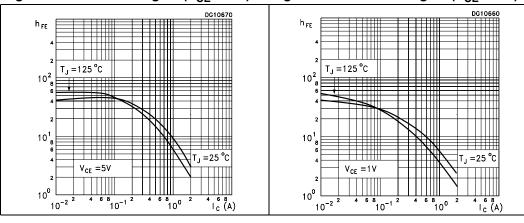
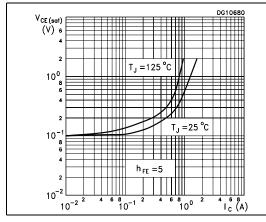
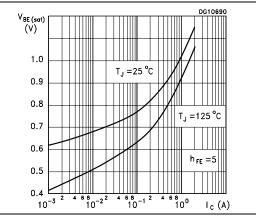


Figure 6. Collector-emitter saturation voltage

Figure 7. Base-emitter saturation voltage

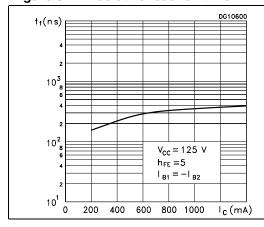




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Figure 8. Resistive load fall time

Figure 9. Resistive load storage time



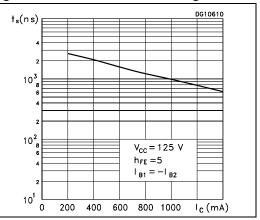
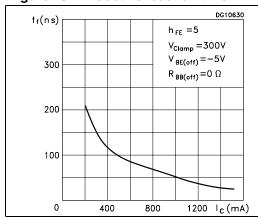


Figure 10. Inductive load fall time

Figure 11. Inductive load storage time



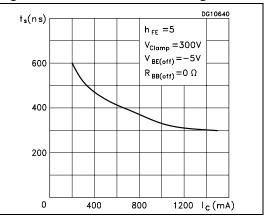
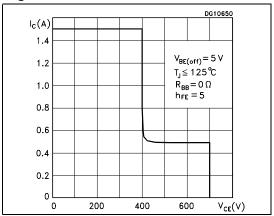


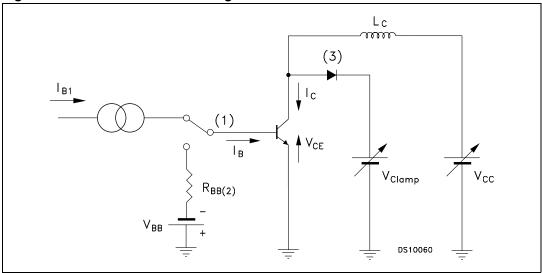
Figure 12. Reverse biased SOA



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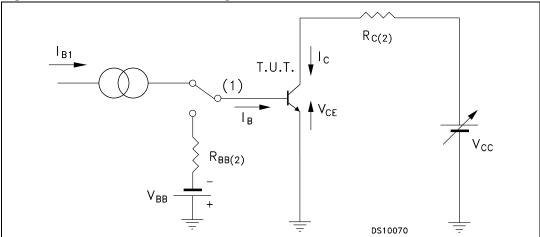
### 2.2 Test circuits

Figure 13. Inductive load switching test circuit



- 1. Fast electronic switching
- 2. Non-inductive resistor
- 3. Fast recovery rectifier

Figure 14. Resistive load switching test circuit



- 1. Fast electronic switching
- 2. Non-inductive resistor

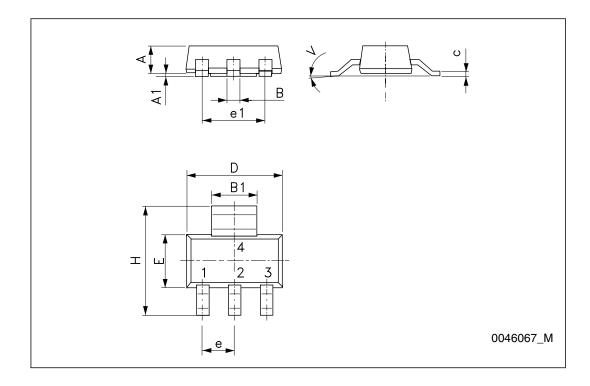
# 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

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#### SOT-223 mechanical data

Dim.		mm.				
	Min.	Тур.	Max.			
А			1.80			
A1	0.02		0.1			
В	0.60	0.70	0.85			
B1	2.90	3.00	3.15			
С	0.24	0.26	0.35			
D	6.30	6.50	6.70			
е		2.30				
e1		4.60				
E	3.30	3.50	3.70			
Н	6.70	7.00	7.30			
V			10 °			





Revision history STN83003

# 4 Revision history

Table 5. Document revision history

Date	Revision	Changes
09-May-2006	1	Initial release.
17-Jan-2007	2	The device's safe operating area curve has been added on page 5.
13-Dec-2010	3	Updated package mechanical data on page 9.

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